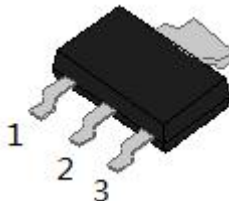
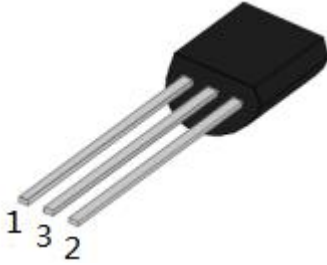
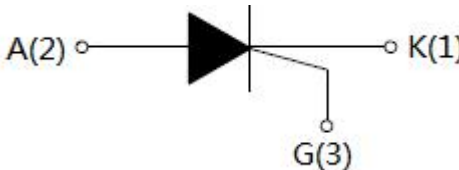


SX011 Series Sensitive gate SCRs

Description

The SX011 SCR series provide high dv/dt rate with strong resistance to electromagnetic interference. They are especially recommended for use on residual current circuit breaker, straight hair, igniter etc.

<p>SX011V</p> 	<p>SX011U</p> 
SOT-223	TO-92
	

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Storage junction temperature range	T_J	-	-40 to +110	°C
Operating junction temperature range	T_{stg}	-	-40 to +150	°C
Repetitive peak off-state voltage	V_{DRM}	-	800	V
Repetitive peak reverse voltage	V_{RRM}	-	800	V
RMS on-state current	$I_{(TRMS)}$	TO-92($T_c=65^\circ\text{C}$)	1	A
		SOT-223($T_c=75^\circ\text{C}$)		
Non repetitive surge peak on-state current($t_p=10\text{ms}$)	I_{TSM}	-	12	A
I^2t value for fusing ($t_p=10\text{ms}$)	I^2t	-	0.72	A^2s
Critical rate of rise of on-state current	di/dt	-	50	$\text{A}/\mu\text{s}$
Peak gate current ($t_p=20 \mu\text{s}$, $T_j=110^\circ\text{C}$)	I_{GM}	-	0.3	A
Peak gate power ($t_p=20 \mu\text{s}$, $T_j=110^\circ\text{C}$)	P_{GM}	-	0.5	W
Average gate power dissipation($T_j=110^\circ\text{C}$)	$P_{G(AV)}$	-	0.1	W

Electrical Characteristics($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Condition	Min.	Typ.	Max.	Units
I_{GT}	$V_D=12\text{V } R_L=33\Omega$	-	40	200	μA
V_{GT}		-	0.6	0.8	V
V_{GD}	$V_D=V_{DRM} T_j=110^\circ\text{C}$	0.2	-	-	V
I_L	$I_G=1.2 I_{GT}$	-	-	5	mA
I_H	$I_T=0.05\text{A}$	-	-	4	mA
dV/dt	$V_D=2/3V_{DRM} T_j=110^\circ\text{C} R_{GK}=1\text{K}\Omega$	100	200	-	V/ μs

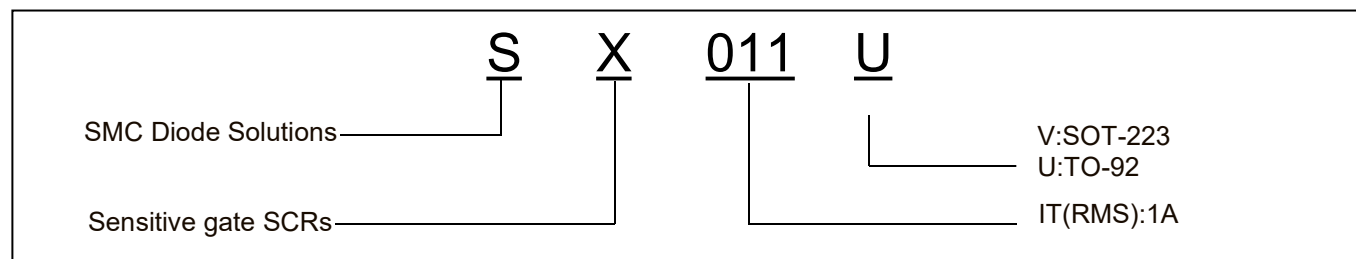
* Pulse width < 300 μs , duty cycle < 2%

Static Characteristics

Symbol	Condition	Max.	Units
V_{TM}	$I_T=2\text{A } t_p=380\mu\text{s}, T_j=25^\circ\text{C}$	1.7	V
I_{DRM}	$V_D=V_{DRM} V_R=V_{RRM}, T_j=25^\circ\text{C}$	5	μA
I_{RRM}	$V_D=V_{DRM} V_R=V_{RRM}, T_j=110^\circ\text{C}$	100	μA

Thermal Resistances

Symbol	Condition	Value	Units
$R_{th(j-c)}$	Junction to case	TO-92	70
		SOT-223	25

Ordering Information


Device	Package	Shipping
SX011V	SOT-223	8000pcs/ reel
SX011VTR	SOT-223	8000pcs/ reel
SX011U	TO-92	2000pcs/ reel
SX011UTR	TO-92	2000pcs/ reel

Ratings and Characteristics Curves

FIG.1: Maximum power dissipation versus RMS on-state current

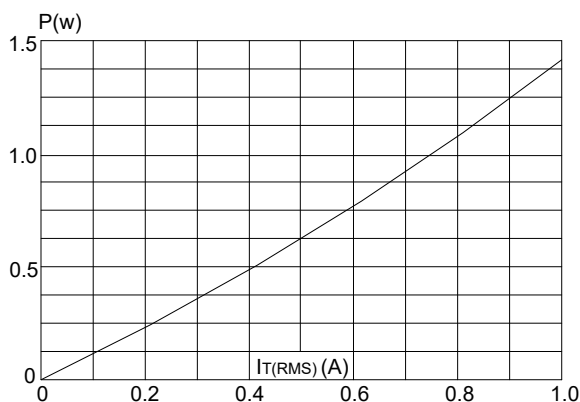


FIG.2: RMS on-state current versus case temperature

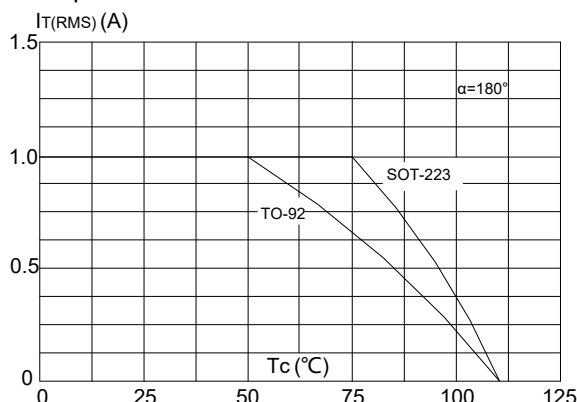


FIG.3: Surge peak on-state current versus number of cycles

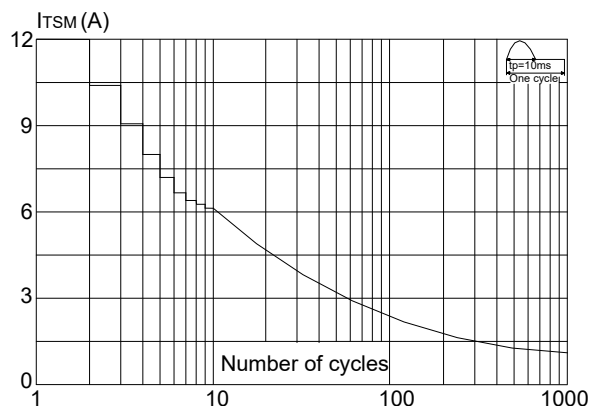


FIG.4: On-state characteristics (maximum values)

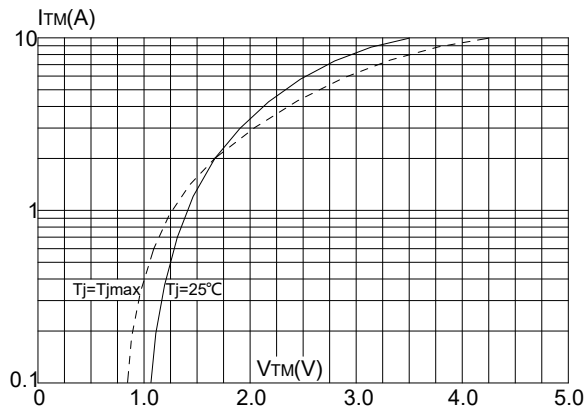


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$ ($di/dt \leq 50\text{A}/\mu\text{s}$)

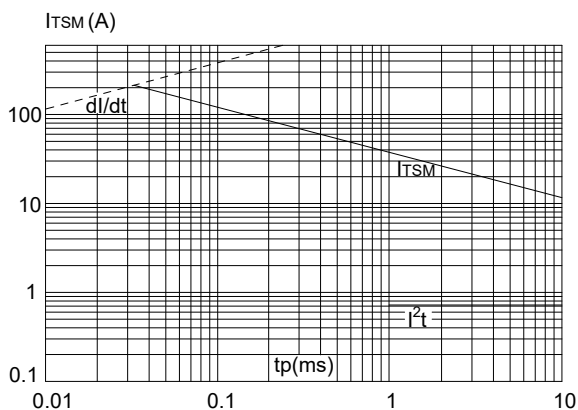
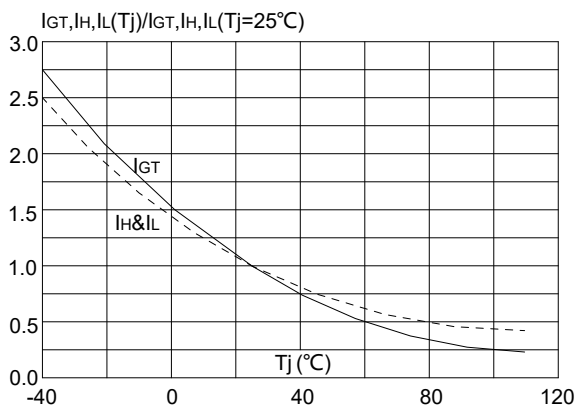
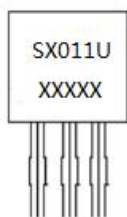


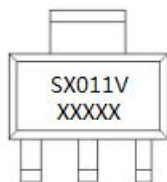
FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature



Marking Diagram



SX011U

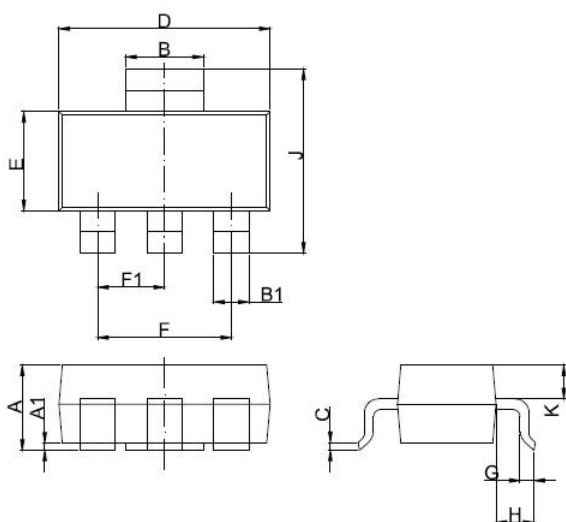


SX011V

Where XXXXX is YYWWL

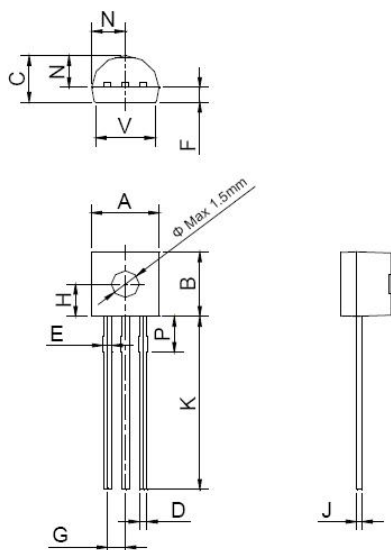
S = SMC
X = Sensitive gate SCRs
011 = Forward Current (1A)
V/U = Package type
YY = Year
WW = Week
L = Lot Number

Mechanical Dimensions SOT-223



SYMBOL	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
L						
A	1.5	1.6	1.8	0.059	0.063	0.071
A1	0.01	0.06	0.10	0.001	0.002	0.004
B	2.9	3.0	3.1	0.114	0.118	0.122
B1	0.6	0.7	0.8	0.024	0.028	0.031
C	0.22	0.26	0.32	0.009	0.010	0.013
D	6.3	6.5	6.7	0.248	0.256	0.264
E	3.3	3.5	3.7	0.130	0.138	0.146
F		4.6			0.181	
F1		2.3			0.091	
G	0.7	0.9	1.1	0.028	0.035	0.043
H	1.50	1.5	2.0	0.059	0.069	0.079
J	6.7	7.0	7.3	0.264	0.276	0.287
K	0.8	0.9	1.0	0.031	0.035	0.039

Mechanical Dimensions TO-92



SYMBOL	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
L						
A	4.45	-	5.20	0.175	-	0.205
B	4.32	-	5.33	0.170	-	0.210
C	3.18	-	4.19	0.125	-	0.165
D	0.407	-	0.533	0.016	-	0.021
E	0.60	-	0.80	0.024	-	0.031
F	-	1.1	-	-	0.043	-
G	-	1.27	-	-	0.050	-
H	-	2.30	-	-	0.091	-
J	0.36	-	0.50	0.014	-	0.020
K	12.70	-	15.0	0.500	-	0.591
N	2.04	-	2.66	0.080	-	0.105
P	1.86	-	2.06	0.073	-	0.081
V	-	-	4.3	-	-	0.169

Technical Data
Data Sheet N2033, Rev.-



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